

Multiscale models of metal plasticity

Part I: Dislocation dynamics to crystal plasticity

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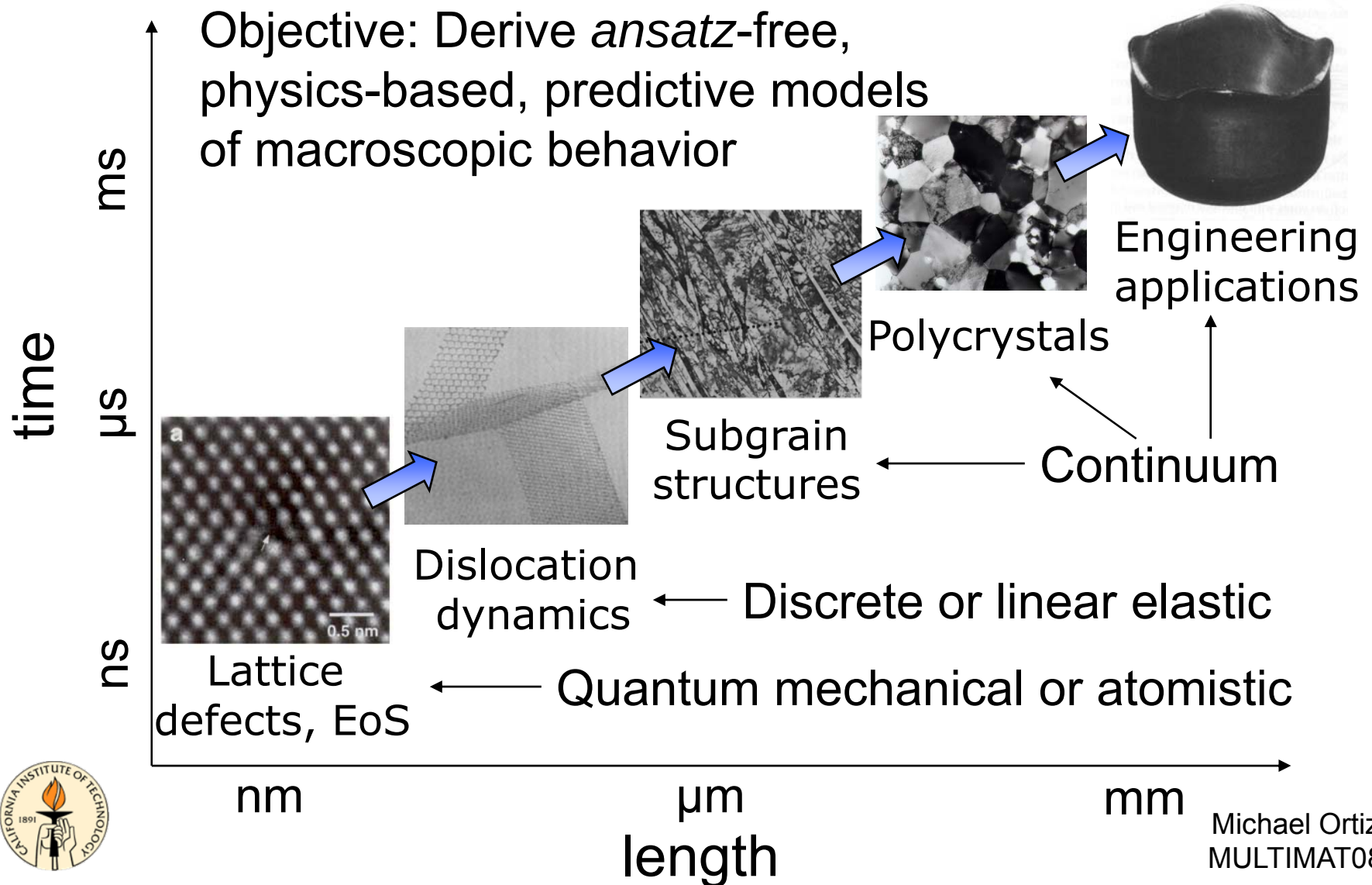
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Metal plasticity

- Behavior of polycrystalline metals is too complex to yield to *ad hoc* modeling:
 - *Polycrystalline texture*
 - *Sub-grain microstructures*
 - *Dislocation dynamics*
 - *Atomistic defect cores*
 - *Pressure/temperature/rate dependency*
 - *Scaling and size effects...*
- Alternative paradigm: Multiscale analysis
 - *Derive rigorous models of effective behavior*
 - *Identify underlying microstructural mechanisms*
 - *Develop high-fidelity (but fast!) physics models...*



Metal plasticity – Multiscale analysis

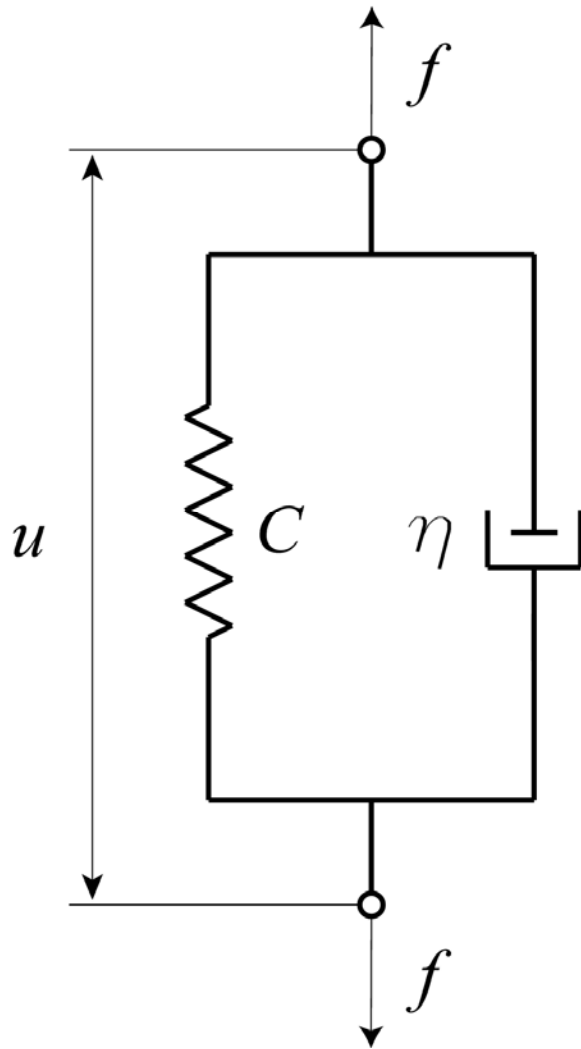


Metal plasticity – Multiscale analysis

- A well-developed body of theory exists for energy minimization problems:
 - *Relaxation*
 - Γ -convergence
 - *Optimal scaling*
- This framework suffices for many applications:
 - *Martensitic phase transitions*
 - *Micromagnetics*
 - *Complex polymers*
- However: Plasticity involves dissipation, hysteresis, irreversible behavior
- Need a theoretical framework that extends CoV to dissipative problems...



Classical rate variational problems



- Kelvin solid IV problem:

$$\left. \begin{aligned} \eta \dot{u}(t) + Cu(t) &= f(t) \\ u(0) &= u_0 \end{aligned} \right\}$$

- Potential energy:

$$E(t, u) = \frac{C}{2}u^2 - f(t)u$$

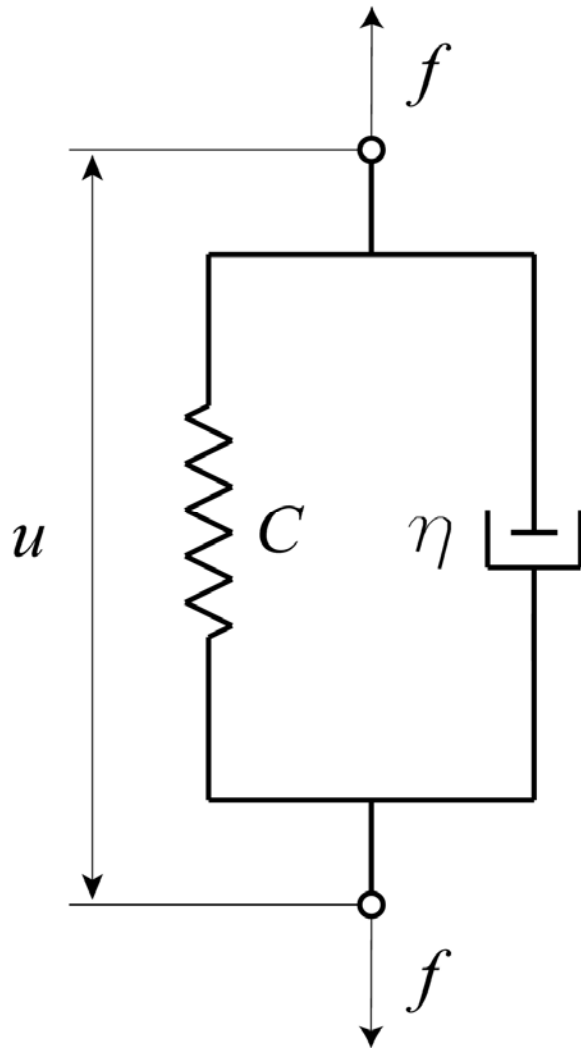
- Dissipation potential: $\Psi(v) = \frac{\eta}{2}v^2$

- Force equilibrium:

$$\partial\Psi(\dot{u}(t)) + DE(t, u(t)) = 0$$



Classical rate variational problems



- Rate potential:

$$G(t, u, v) \equiv \Psi(v) + DE(t, u) v$$

- Rate problem: Given t, u ,

$$\min_v G(t, u, v)$$

- Euler-Lagrange equations:

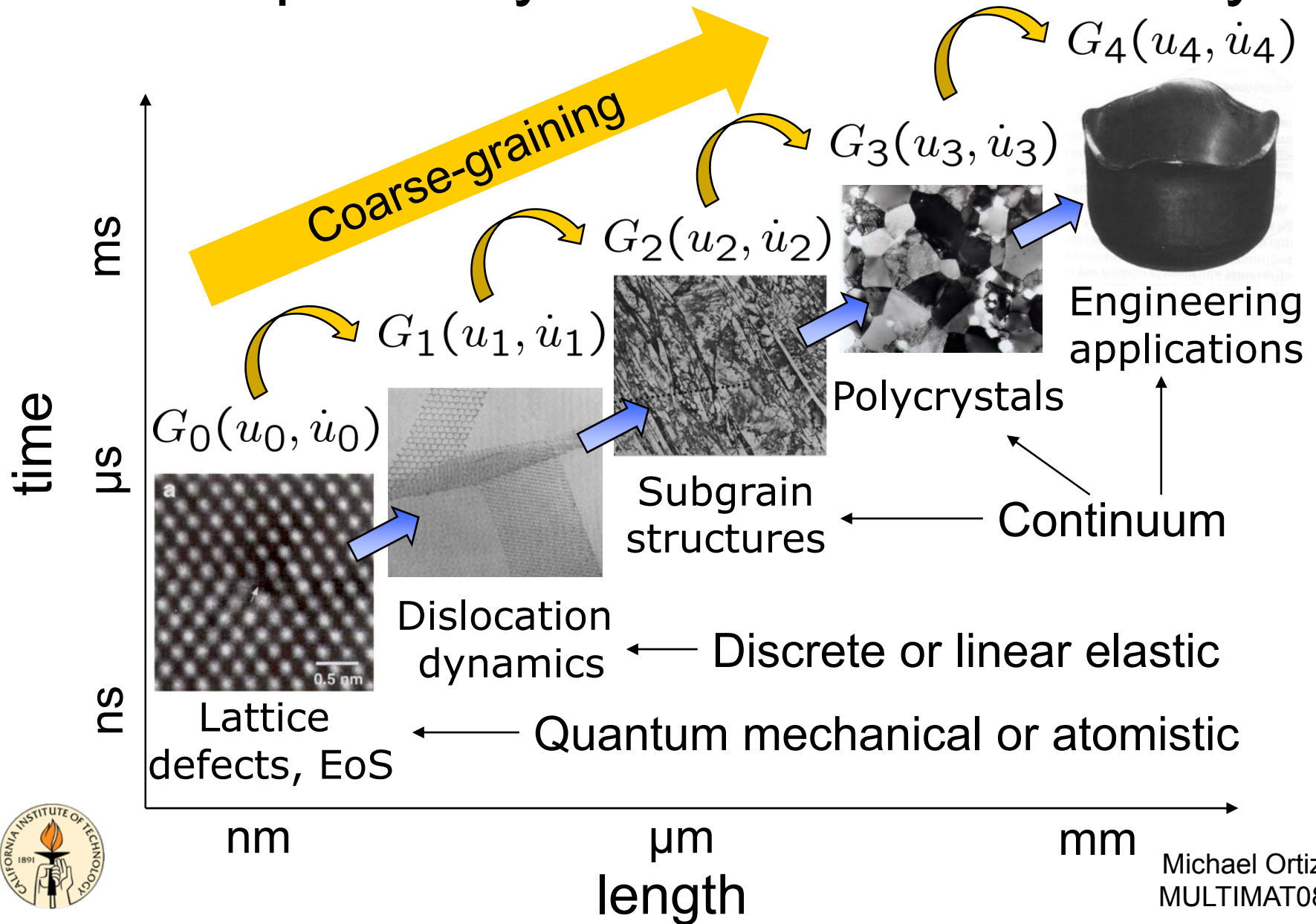
$$\partial \Psi(v) + DE(t, u) = 0$$

- IV problem: For $t \in [0, T]$,

$$\left. \begin{aligned} v(t) &\in \operatorname{argmin} G(t, u(t), \cdot) \\ \dot{u}(t) &= v(t), \quad u(0) = u_0 \end{aligned} \right\}$$



Metal plasticity – Multiscale hierarchy



Energy-dissipation functionals

- Energy-dissipation functional: For $\epsilon > 0$,

$$F_\epsilon(u) = \int_0^T e^{-t/\epsilon} G(t, u, \dot{u}) dt$$

- Minimum principle: $\mathbb{Y} = \{u : [0, T] \rightarrow Y\}$,

$$\inf_{u \in \mathbb{Y}} F_\epsilon(u)$$

- Euler-Lagrange eqs., $G(u, \dot{u}) = \Psi(\dot{u}) + DE(u)\dot{u}$,

$$\underline{-\epsilon D^2 \Psi(\dot{u}) \ddot{u} + D\Psi(\dot{u}) + DE(t, u) = 0}$$

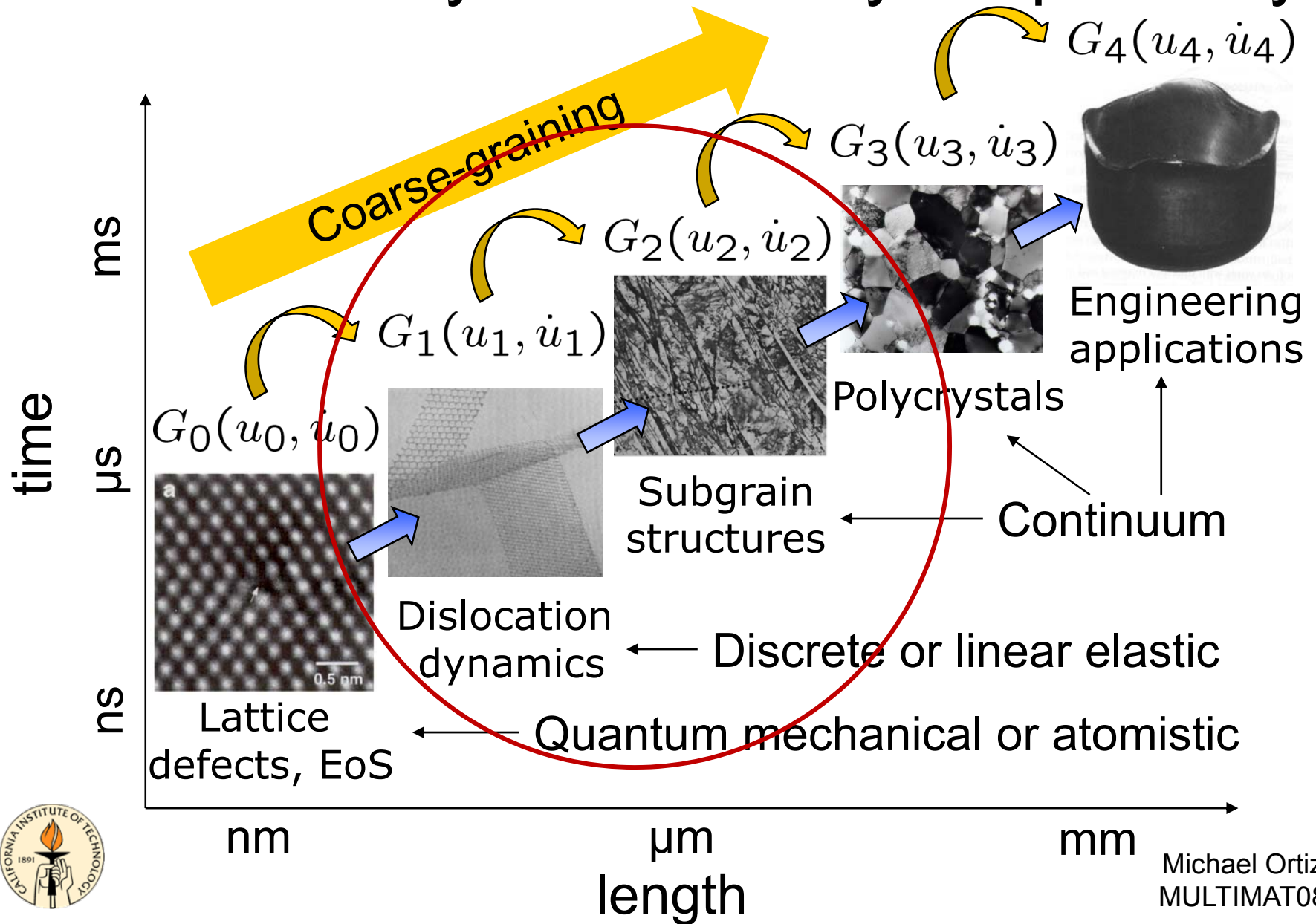
- Relaxation: $sc^- F_\epsilon(u) \stackrel{?}{=} \underbrace{\int_0^T e^{-t/\epsilon} \underline{\bar{G}_\epsilon(t, u, \dot{u})} dt}_{\text{local?}}$

- Causal limit: $\epsilon \rightarrow 0?$

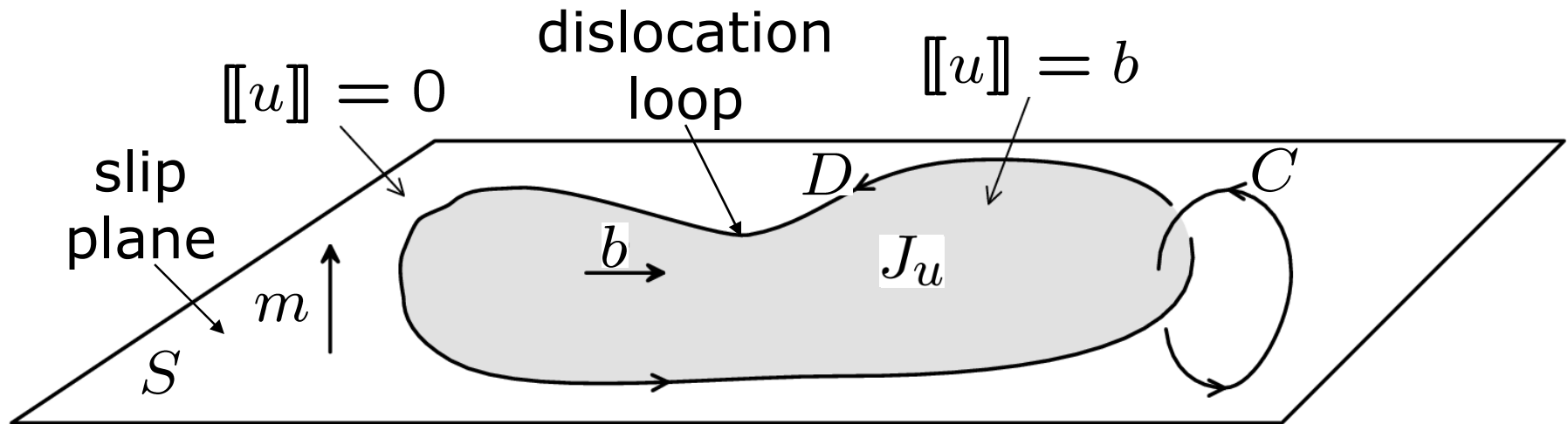


local?

Dislocation dynamics to crystal plasticity



LE dislocations - Kinematics



- Volterra dislocation: $u \in SBV^2(\Omega)$ such that

$$Du = \underbrace{\nabla u \mathcal{L}^3}_{\text{elastic deformation}} + \underbrace{[[u]] \otimes m \mathcal{H}^2}_{\text{plastic deformation (currents)}} \llcorner J_u \equiv \beta^e + \beta^p$$

elastic deformation plastic deformation (currents)

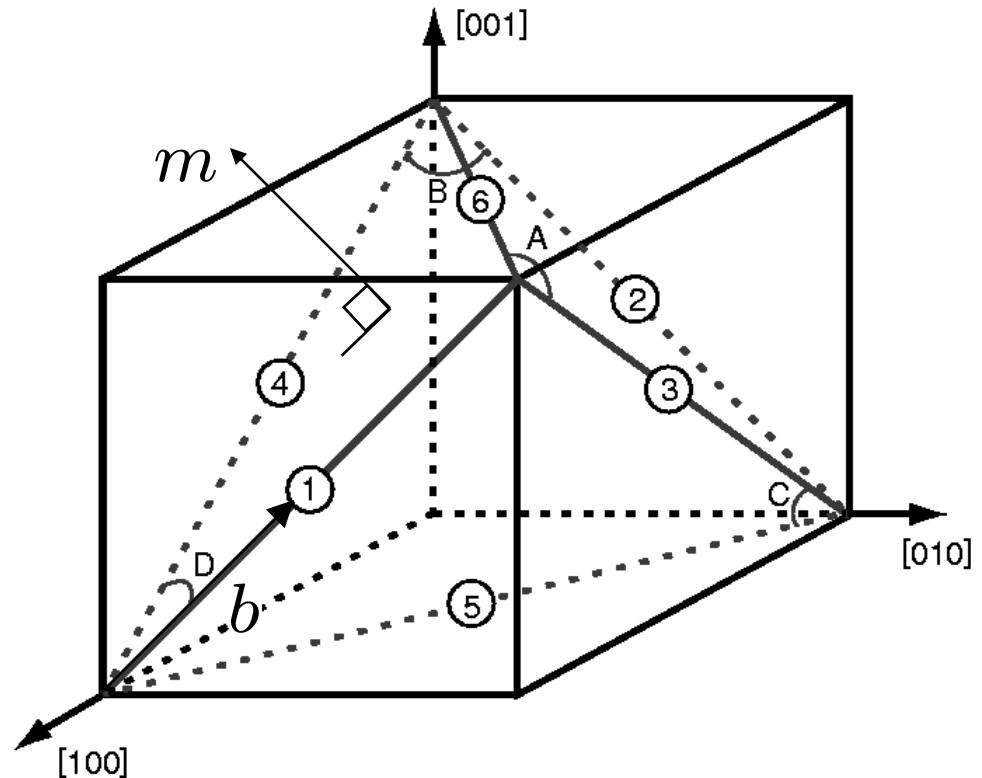
- Dislocation density: $\alpha = \partial \beta^p$

- Conservation of Burgers vector: $\partial \alpha = \partial^2 \beta^p = 0$



LE dislocations – Constrained theory

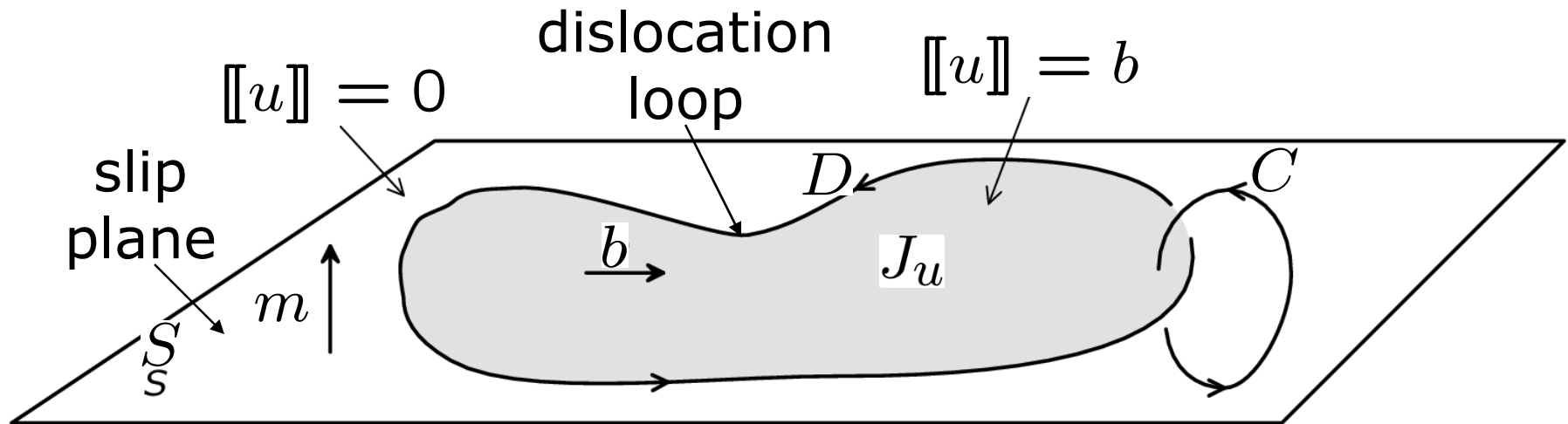
- Mobility: $J_u \subset \{\text{closed-packed planes of lattice}\}$
- Energy: $\beta^p/d =$ lattice-preserving deformation
- Energy: $\llbracket u \rrbracket$ in $\text{span}_{\mathbb{Z}}(\{\text{shortest translation vectors of lattice}\}) * \underbrace{\varphi_\epsilon}_{\text{core-cutoff mollifier}}$



The 12 slip systems of fcc crystals (Schmidt and Boas nomenclature)
 $b \in \mathcal{S}(1, 1, 0), \quad m \in \mathcal{S}(1, 1, 1)$



LE dislocations - Kinematics



- Volterra dislocations: $u \in SBV^2(\Omega)$ such that

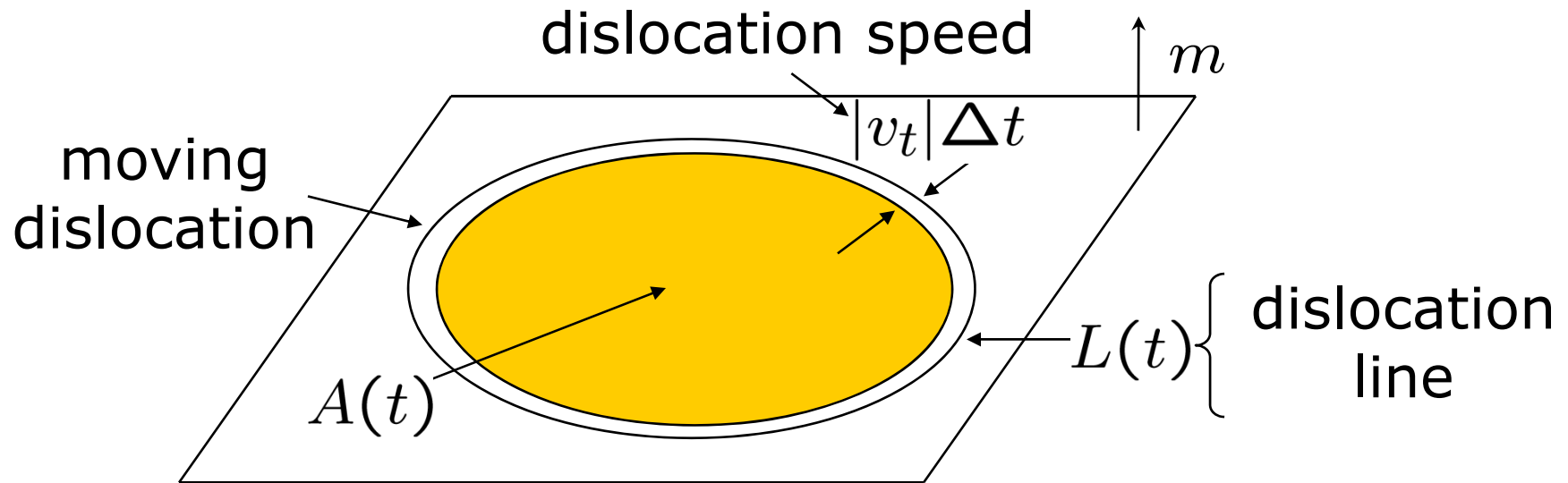
$$Du = \nabla u \mathcal{L}^3 + [[u]] \otimes m \mathcal{H}^2 \llcorner J_u$$

- Energy: $E(u) = \int_{\Omega} \frac{1}{2} |\epsilon(u)|^2 dx,$

where: $\epsilon(u) = \frac{1}{2}(\nabla u + \nabla u^T) \equiv$ elastic strain



LE dislocations - Dissipation



- Dislocation flux: $\forall \varphi \in C_0^1([0, T]), \forall f \in C_0(\Omega),$

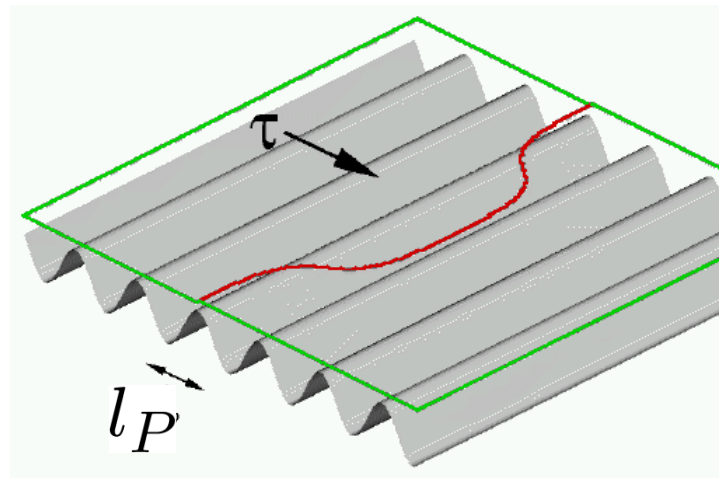
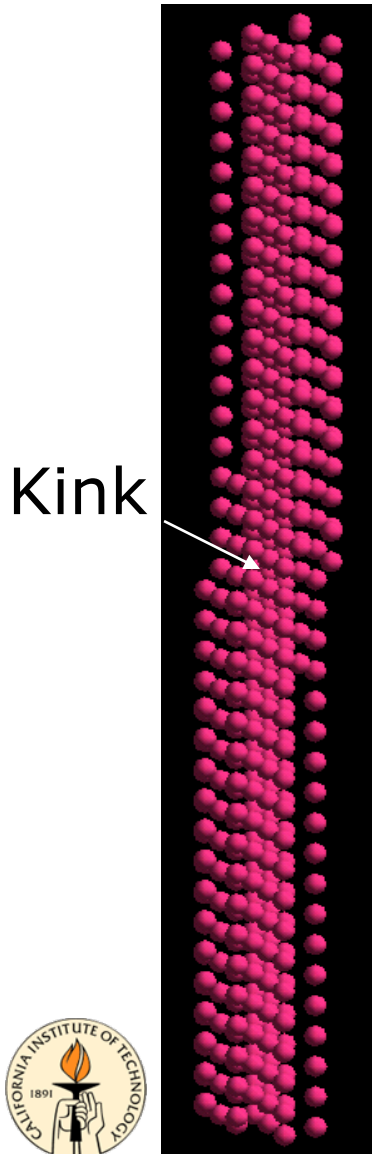
$$\int_0^T \dot{\varphi} \left\{ \int \llbracket u \rrbracket \otimes m f d\mathcal{H}^2 \right\} dt = - \int_0^T \varphi \int_{\Omega} f \underline{d\mu_t}(x) dt$$
- Dislocation velocity: $\mu_t = -\alpha \times \underline{v_t}$



• Dissipation:

$$\Psi(\dot{u}, u) = \int_{J_u} \psi(v_t) d\mathcal{H}^2$$

LE dislocations – Dissipation



Stainier, L., Cuitino, A. and Ortiz, M., *JMPS*, **50** (2002) 1511-1554.

- From transition-state theory:

$$\psi(v) = \psi_0 \left(\frac{v}{v_0} \operatorname{asinh} \frac{v}{v_0} - \sqrt{1 + \frac{v^2}{v_0^2}} \right),$$

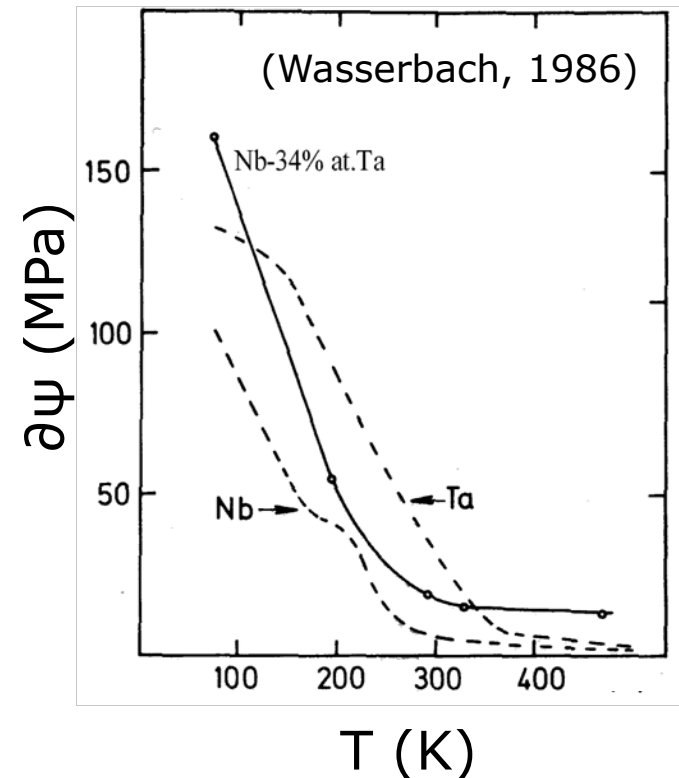
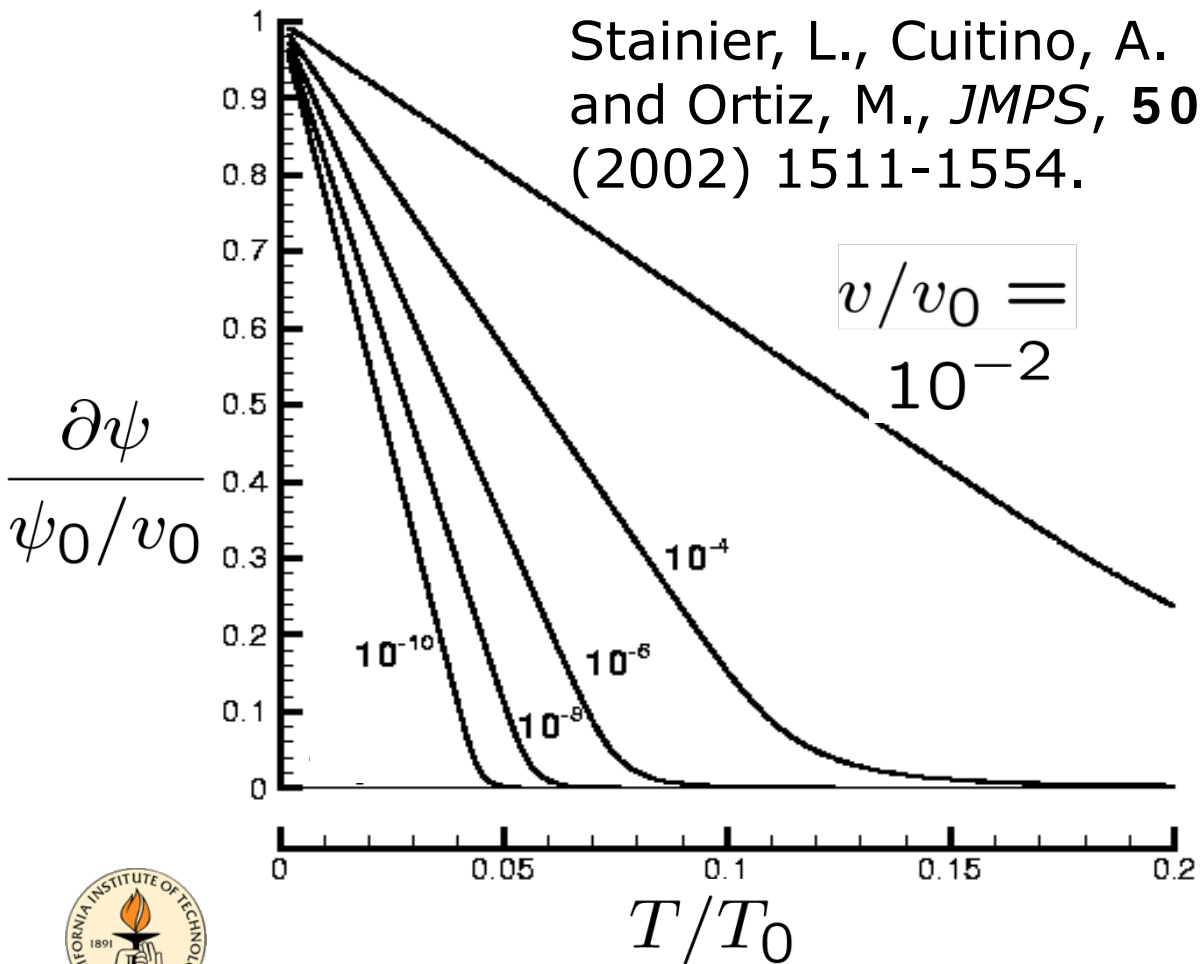
ψ_0, v_0 calculated from atomistic models

Wang, G. *et al.*, *J. Computer Aided Materials Design*, 2001)



LE dislocations – Dissipation

- Validation of transition-state theory model:



LE dislocations – Energy-dissipation

- Rate potential: $G(u, \dot{u}) = \Psi(\dot{u}) + DE(u)\dot{u}$

- Energy: $E(u) = \int_{\Omega} \frac{1}{2} |\epsilon(u)|^2 dx$

- Dissipation: $\Psi(\dot{u}, u) = \int_{J_u} \psi(v_t) d\mathcal{H}^2$

- Energy-dissipation functional: For $\epsilon > 0$,

$$F_{\epsilon}(u) = \int_0^T e^{-t/\epsilon} G(t, u, \dot{u}) dt \longrightarrow \inf!$$

- Relaxation: $sc^{-} F_{\epsilon}(u)?$
 - Causal limit: $\epsilon \rightarrow 0?$
- } $\longrightarrow$ Crystal plasticity!

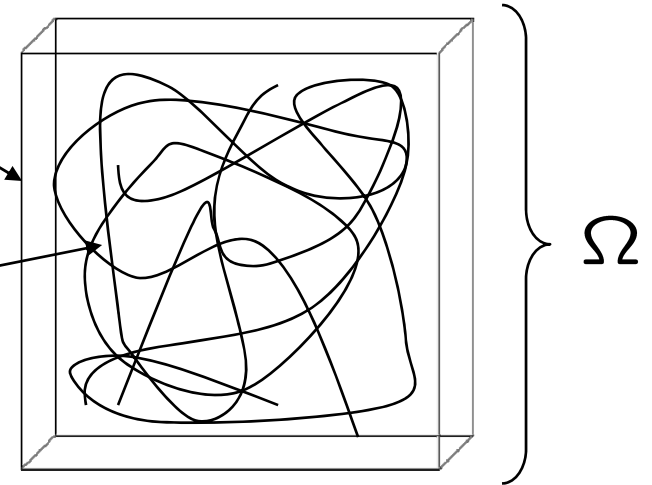
Problems are open!



LE dislocations – Energy models

$$u = \bar{\beta}x \text{ (affine BC)}$$

β^p, α given!



- Average plastic deformation:

$$\bar{\beta}^p = \frac{1}{|\Omega|} \int_{J_u} \llbracket u \rrbracket \otimes m \, d\mathcal{H}^2$$

- Elastic energy: $\inf_u \int_{\Omega \setminus S_u} \left(\frac{1}{2} |\epsilon(u)|^2 - \epsilon(u) \cdot \epsilon^p \right) dx$

$$= |\Omega| \left(\frac{1}{2} |\bar{\epsilon}|^2 - \bar{\epsilon} \cdot \bar{\epsilon}^p \right) + E(\alpha)$$

strain energy

stored energy



LE dislocations – Energy models

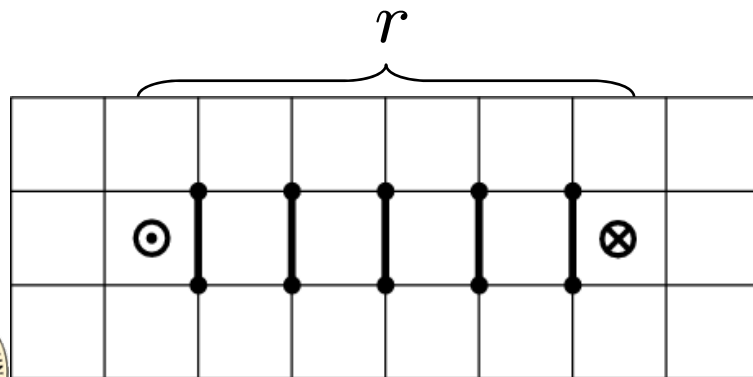
- Stored energy: $E(\alpha) = \int \int \underbrace{\text{tr}[d\alpha^T(x)\Gamma(x,y)d\alpha(y)]}_{\text{nonlocal!}}$

where: $\Gamma(x, y) =$ nonlocal!

$$\int_{\Omega} [\nabla G(x, z) \cdot \nabla G(y, z) I - \nabla G(x, z) \otimes \nabla G(x, z)] dz$$

and: $G = \Delta^{-1} \equiv$ Green's function of the Laplacian

- Example: Dislocation dipole



$$\leftarrow \frac{E}{L} \sim \frac{Gb^2}{2\pi} \log \frac{r}{\epsilon} + b\tau r$$



LE dislocations – Energy models

- Conjecture: For sufficiently dilute dislocations,

$$\Gamma - \lim_{h \rightarrow \infty} E_h(\alpha) = \int \underbrace{T(\alpha/|\alpha|) d|\alpha|}_{\text{local line tension approximation!}}$$

local line tension approximation!

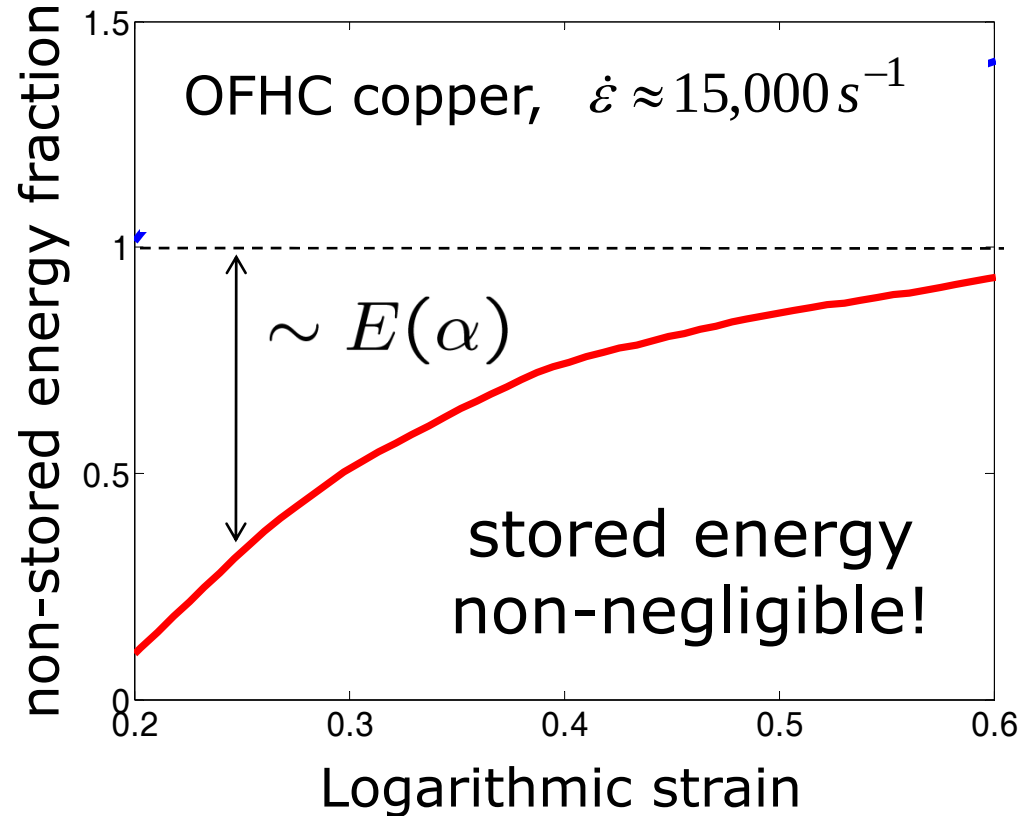
- True in 2D: M. Ponsiglione, *SIAM J. Math. Anal.* **39** (2008) no. 2, 449-469; A. Garroni, G. Leone, M. Ponsiglione, preprint (2008).
- True in 2.5D: Garroni, S. Müller, *SIAM J. Math. Anal.*, **36** (2005) no. 6, 1943–1964; S. Cacace, A. Garroni, preprint (2008).
- Frequently used approximation: $E(\alpha) \approx 0$.



LE dislocations – Energy models



Kolsky (split Hopkinson)
pressure bar

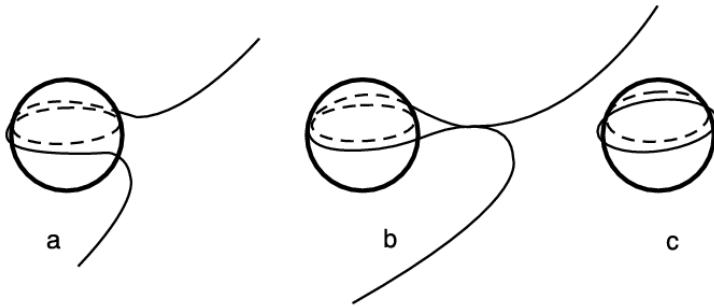


Fraction of total work dissipated as heat
(Rittel, D, Ravichandran, G, Lee, S, *Mechanics of Materials*, **34** (2002) 627-642)

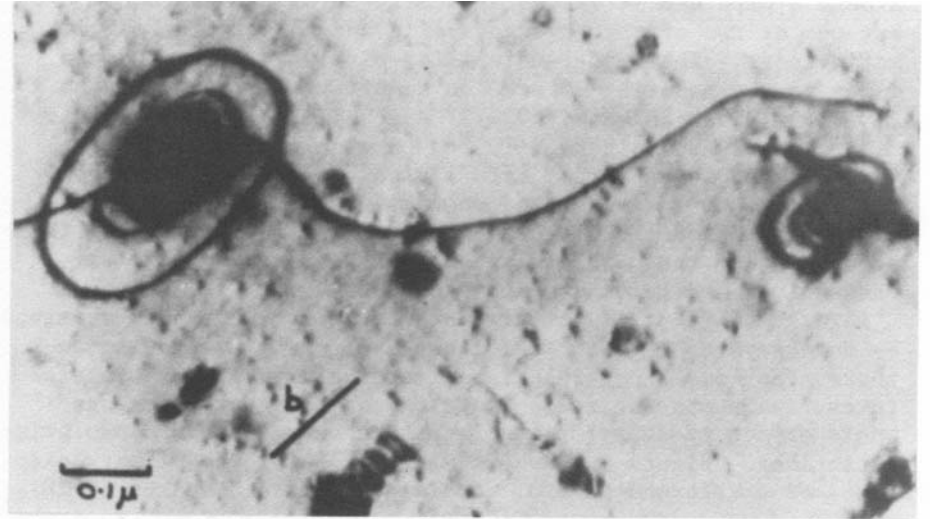


LE dislocations – Dissipation models

- Example: Precipitates.



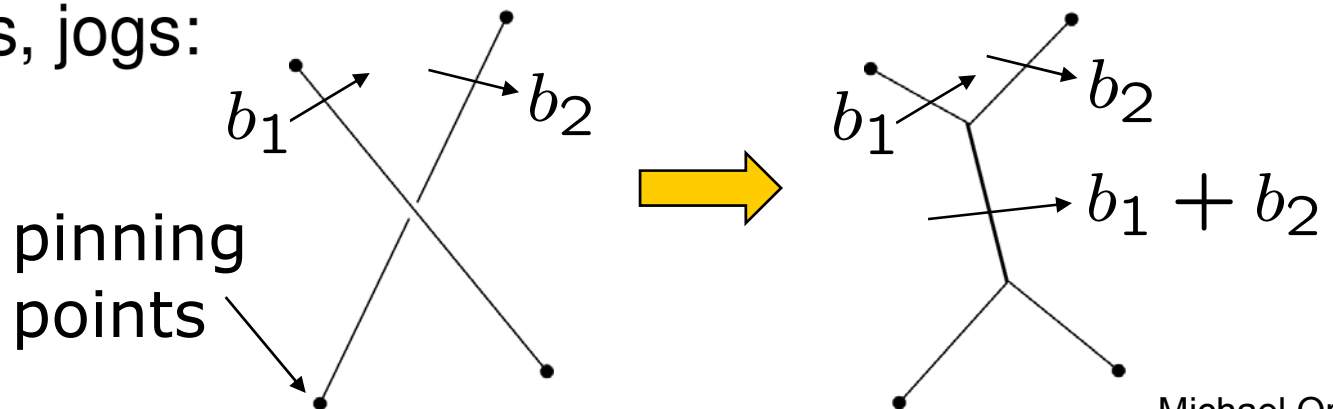
Impenetrable obstacles



(Humphreys and Hirsch '70)

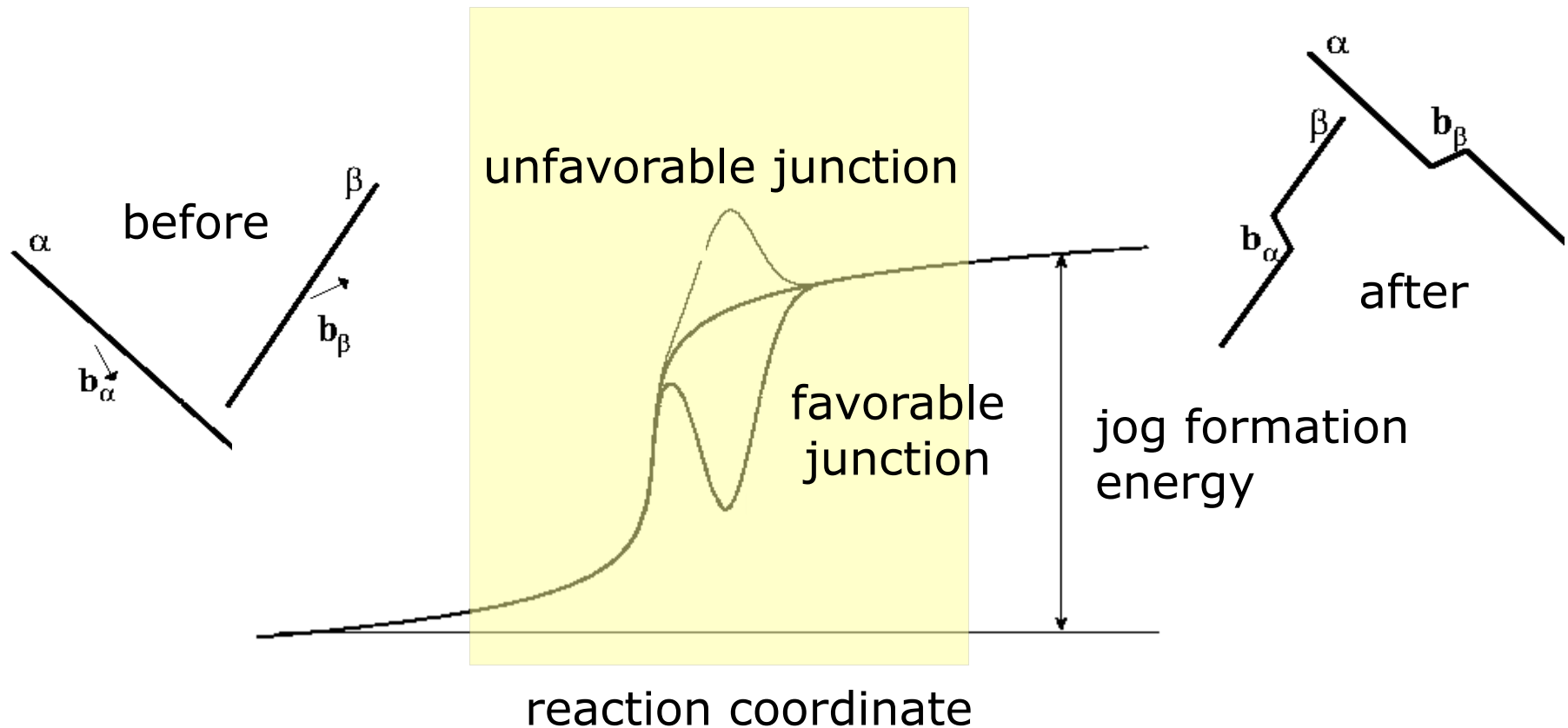
- Junctions, jogs:

([movie](#))
(LLNL)



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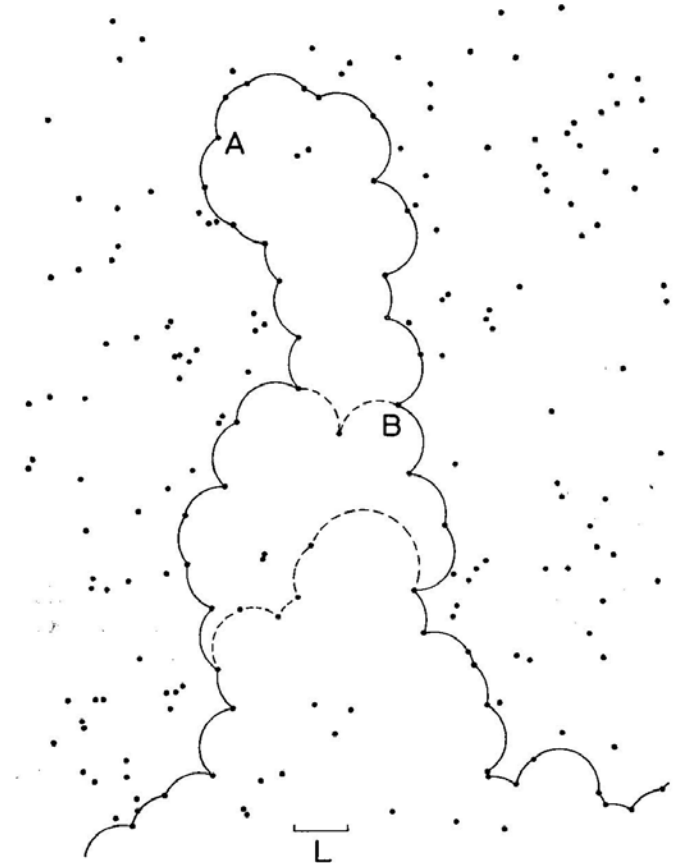
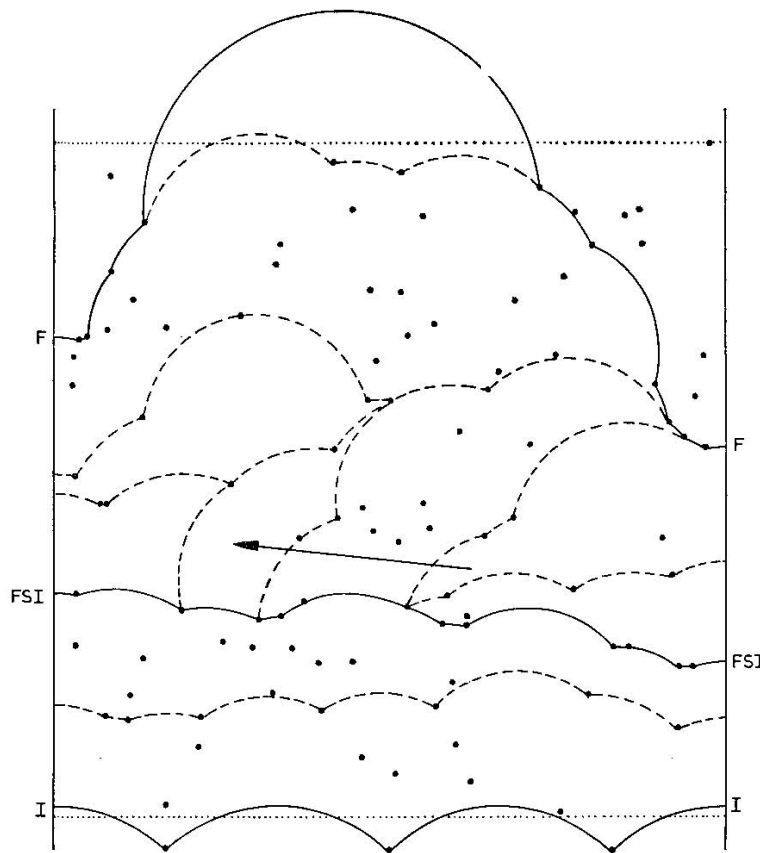
LE dislocations – Dissipation models



Dissipation at junctions and jogs
(Stainier, L., Cuitino, A., Ortiz, M., *JMPS*, **50**
(2002) 1511-1554)



LE dislocations – Energy-dissipation models



Dislocation motion through random obstacle array
(Foreman, A.J.E., Makin, M.J., *Phil. Mag.*, **14** (1966) 911)

- Plastic work: $W^p \sim \rho^{1/2} \gamma^{3/2}$, where:
 $\rho \equiv$ obstacle density, $\gamma \equiv$ slip strain



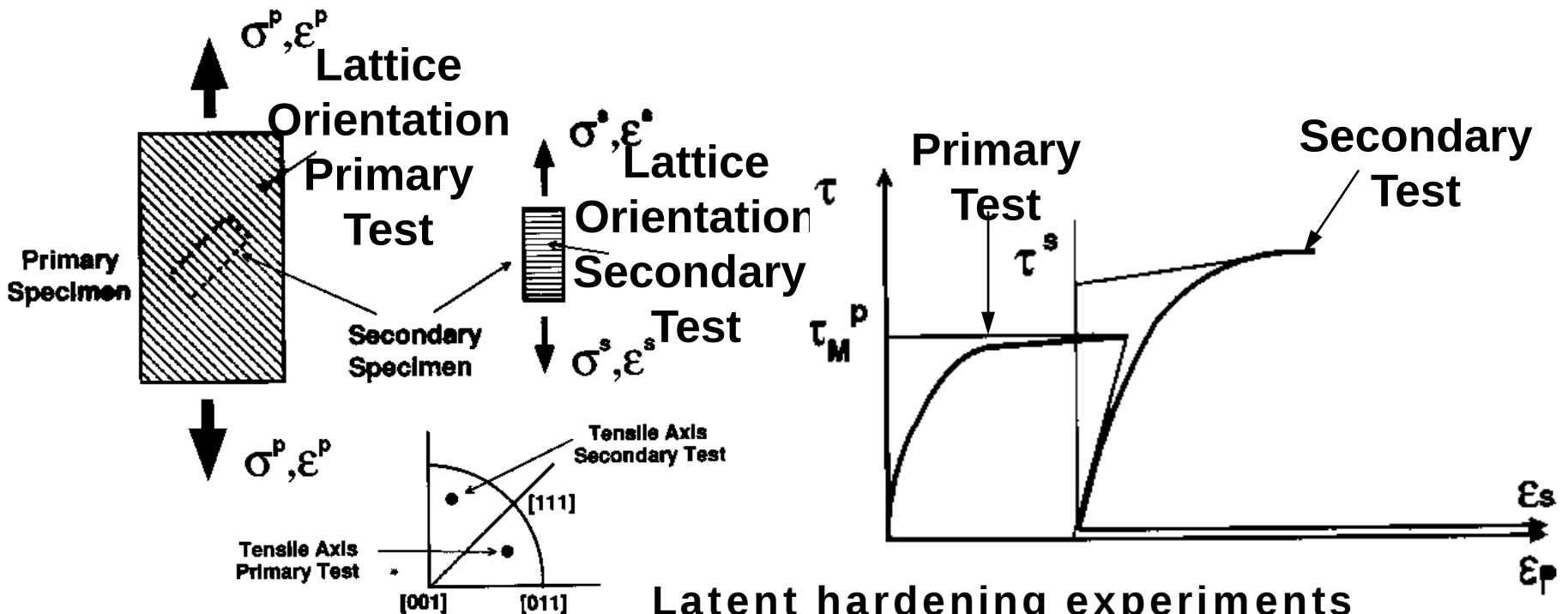
LE dislocations – Energy-dissipation models

- Forest hardening: Dislocations in secondary systems supply obstacles to the motion of dislocations on primary systems
- Dislocation multiplication: Dislocation density increases as a result of slip activity due to
 - *Activation of fixed sources*
 - *Dynamic sources (cross slip)*
 - *Anihilation*
- Strong latent hardening: High rate of hardening of primary system due to activity on secondary systems



([movie](#))
(LLNL)

Junctions – Strong latent hardening



Latent hardening experiments

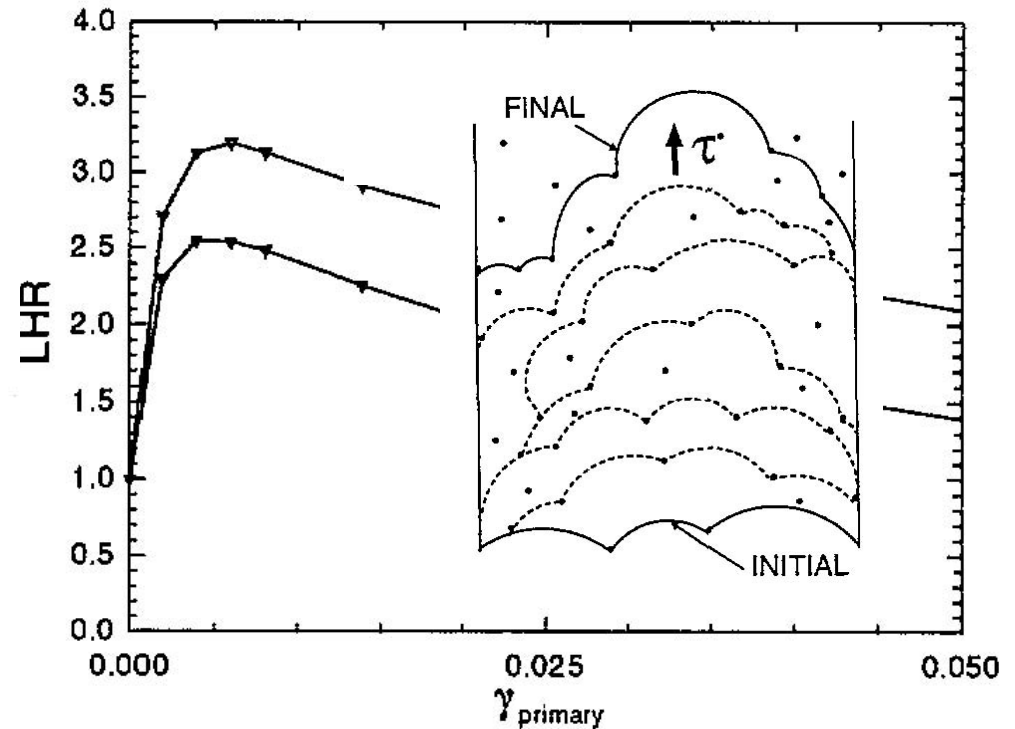
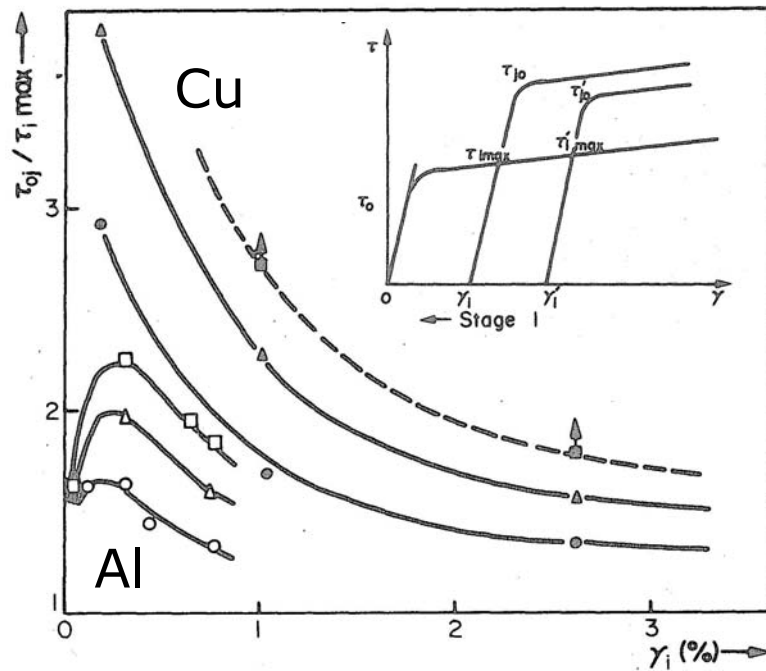
UF Kocks, *Acta Metallurgica*, 8 (1960) 345

UF Kocks, *Trans. Metall. Soc. AIME*, 230 (1964) 1160

- Strong latent hardening: Crystals much 'prefer' to activate a single slip system at each material point, though the active system may vary from point to point



LE dislocations – Energy-dissipation models



Measured latent hardening ratios
(Franciosi, P., Berveiller, M.,
and Zaoui, A., *Acta Metall.*, 28
(1980) 273-283)

Latent hardening ratios predicted
from line tension percolation
model, multiple slip and
dislocation multiplication



(Cuitino, A. and Ortiz, M., *Modelling
Simul. Mater. Sci. Engr.*, 1 (1992) 225-263)

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Dislocation dynamics to crystal plasticity

- The problem of deriving single crystal plasticity from dislocation dynamics remains open in general
- Mathematical formulation of the problem: Relax dislocation-dynamics energy-dissipation functional, pass to the causal limit
- Many important features of crystal plasticity are understood qualitatively from experiments, microscopy and engineering models
- Most important among those features are:
 - *Crystallographic nature of plastic slip in crystals*
 - *Strong latent hardening under multiple slip*
- These features give rise to microstructure...

